

Form PTO-1449		ATTY DOCKET NO. 24500-000015/US	APPLICATION NO. 10/152,519 NEW APPLICATION
INFORMATION DISCLOSURE CITATION IN AN APPLICATION <small>(Use several sheets if necessary)</small>		APPLICANT(S) Valerie BOUSQUET et al.	CONF. NO. Not Yet Assigned
		FILING DATE February 23, 2005	GROUP Not Yet Assigned

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
AKS	US 5,602,418	02/11/1997	Hideaki IMAI et al.			

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION	
						YES	NO
AKS	EP 1 061 564 A2	12/20/2000	EUROPE			X	
AKS	EP 1 164 210 A2	12/19/2001	EUROPE			X	

OTHER DOCUMENTS (Include Name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.)

AKS	Shuji NAKAMURA et al., "Candela-class high-brightness InGaN/AlGaN double-heterostructure blue-light-emitting diodes", Applied Physics Letters, American Institute of Physics, New York, US, Vol. 64, No. 13, March 28, 1994, pages 1687-1689
AKS	Shuji NAKAMURA et al., "Superbright Green InGaN Single-Quantum-Well-Structure Light-Emitting Diodes", Japanese Journal of Applied Physics, Publication Office Japanese Journal of Applied Physics, Tokyo, Japan, Vol. 34, No. 10B, Part 2, October 15, 1995, pages L1332-L1335

EXAMINER	DATE CONSIDERED
Aski Kumar Sarkar	12/18/07

EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.